

ABC847BV-HF (NPN+NPN)

RoHS Device

Halogen Free

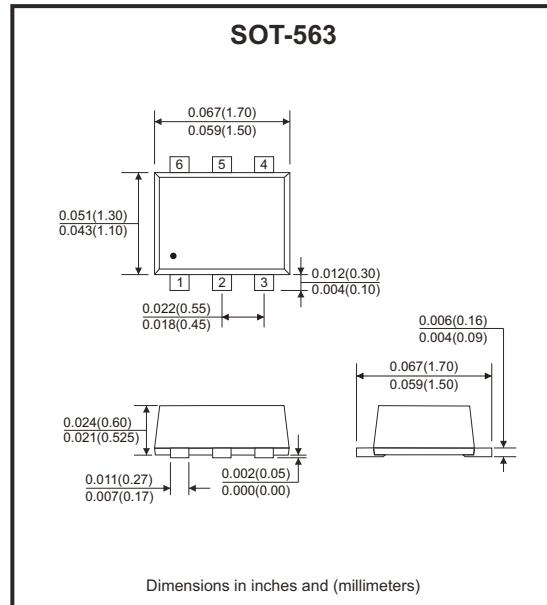


Features

- Ultra-small surface mount package.
- AEC-Q101 Qualified.

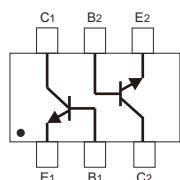
Mechanical data

- Case: SOT-563, molded plastic.
- Molding compound: UL flammability classification rating 94V-0.
- Terminals: Tin-plated; solderability-per MIL-STD-202, method 208.



Circuit Diagram

B :Base
E :Emitter
C :Collector



Maximum Ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	45	V
Emitter-base voltage	V _{EBO}	6	V
Collector current-continuous	I _C	100	mA
Collector current-peak	I _{CM}	200	mA
Power dissipation (Note 1)	P _C	150	mW
Thermal resistance, junction to ambient (Note 1)	R _{θJA}	833	°C/W
Operating junction temperature range	T _J	-55 to +150	°C
Storage temperature range	T _{STG}	-55 to +150	°C

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.

Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 10µA, I _B = 0	50			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = 10mA, I _B = 0	45			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E = 1µA, I _C = 0	6			V
Collector cut-off current	I _{CBO}	V _{CB} = 30V, I _E = 0			15	nA
Emitter-base cut-off current	I _{EBO}	V _{EB} = 5V, I _C = 0			100	nA
Collector-emitter cut-off current	I _{CEO}	V _{CE} = 30V, I _B = 0			1	mA
DC current gain	h _{FE}	V _{CE} = 5V, I _C = 2mA	200		450	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 10mA, I _B = 0.5mA			0.25	V
		I _C = 100mA, I _B = 5mA			0.60	
Base-emitter saturation voltage	V _{BE(sat)}	I _C = 10mA, I _B = 0.5mA		0.7	0.90	V
		I _C = 100mA, I _B = 5mA		0.9	1.10	
Base-emitter voltage	V _{BE(on)}	V _{CE} = 5V, I _C = 2mA	0.58	0.66	0.70	V
		V _{CE} = 5V, I _C = 10mA			0.77	
Transition frequency	f _T	V _{CE} = 5V, I _C = 10mA, f = 100MHz	100			
Emitter input capacitance	C _{ib}	V _{CB} = 0.5V, I _C = 0, f = 1MHz		13.28		pF
Collector output capacitance	C _{ob}	V _{CB} = 10V, I _E = 0, f = 1MHz		1.52		pF

Small Signal Transistor

Comchip
SMD Diode Specialist

Rating and Characteristic Curves (ABC847BV-HF)

Fig.1 - h_{FE} — I_c

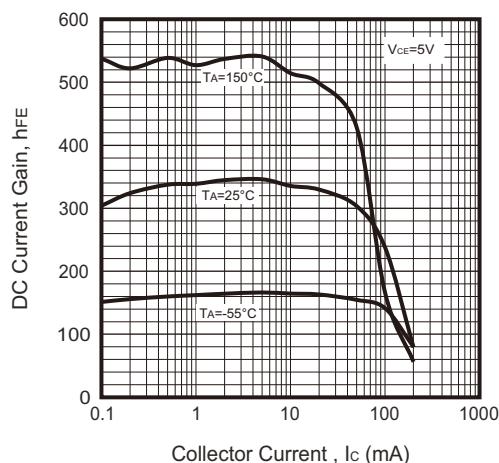


Fig.2 - $V_{CE(sat)}$ — I_c

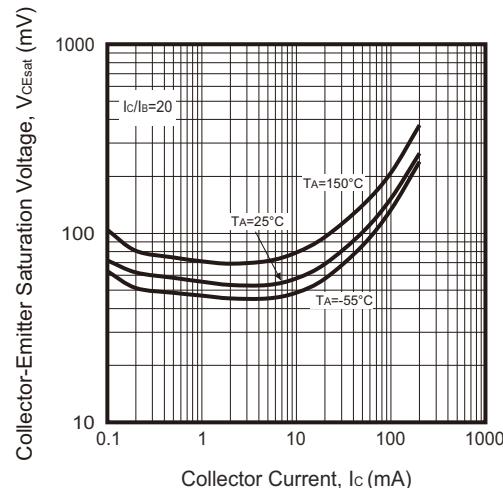


Fig.3 - $V_{BE(sat)}$ — I_c

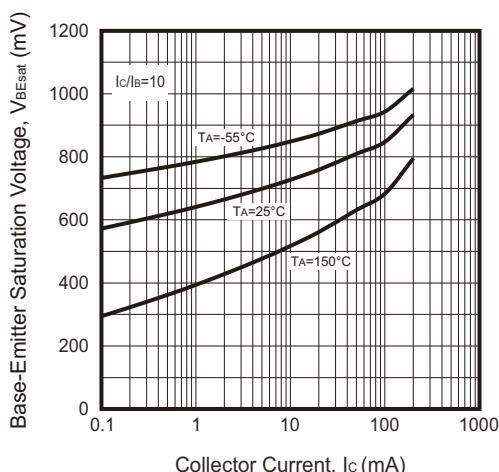
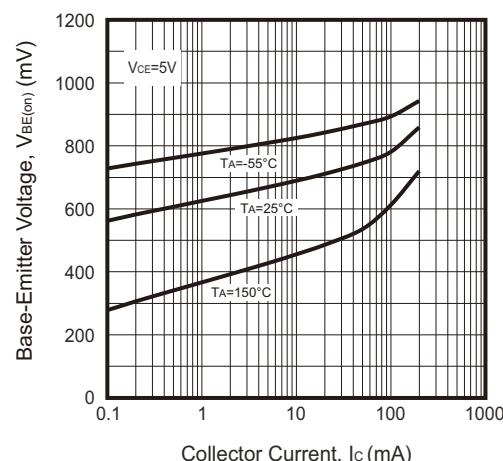
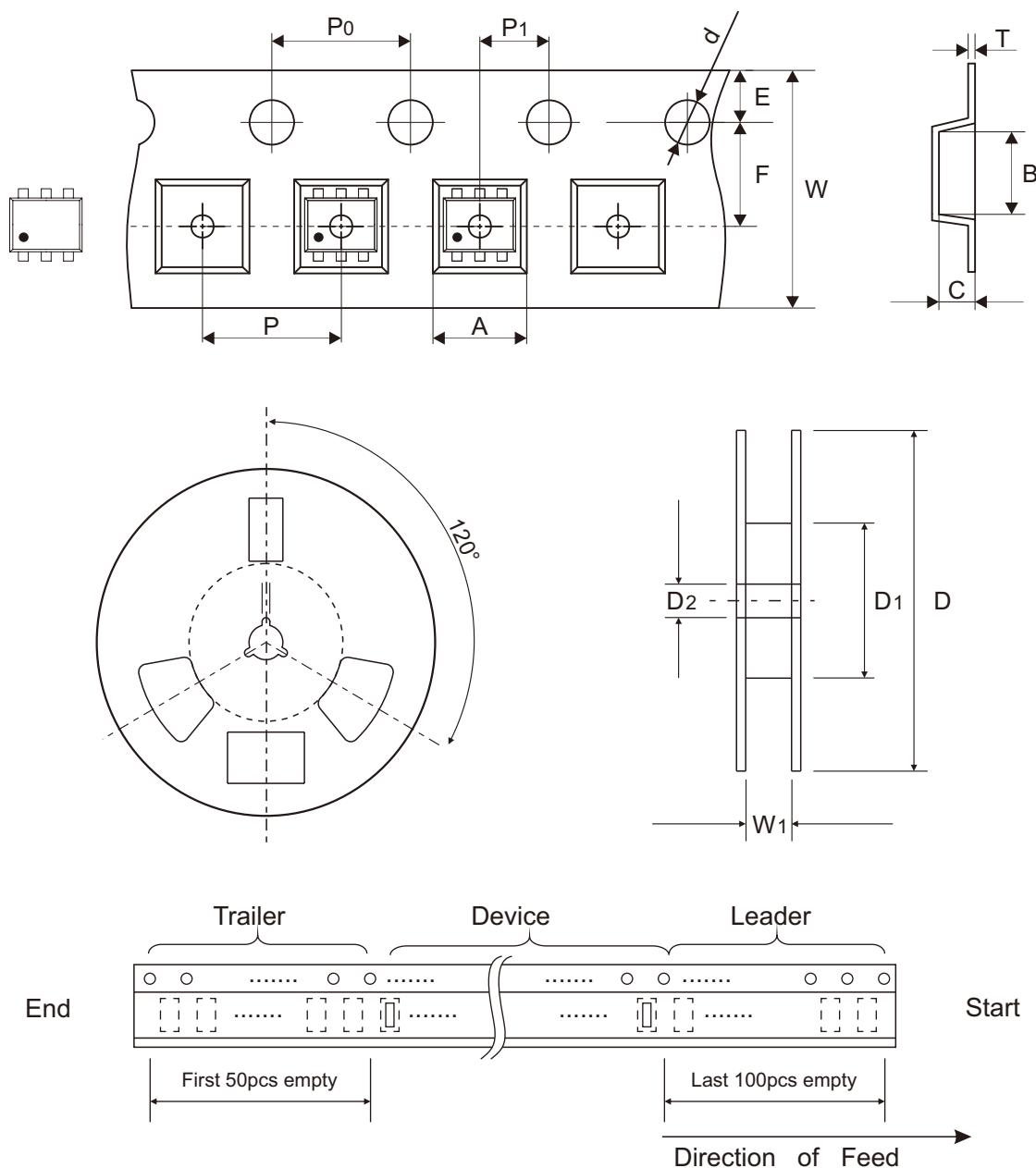


Fig.4 - $V_{BE(on)}$ — I_c



Reel Taping Specification

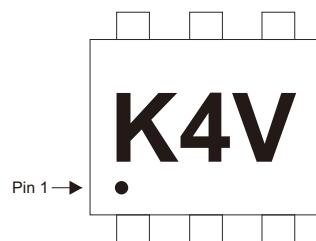


SOT-563	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	1.78 ± 0.05	1.78 ± 0.05	0.69 ± 0.05	1.55 ± 0.05	178 ± 1.00	54.00 ± 0.50	13.00 ± 0.50
	(inch)	0.070 ± 0.002	0.070 ± 0.002	0.027 ± 0.002	0.061 ± 0.002	7.008 ± 0.039	2.126 ± 0.020	0.512 ± 0.020

SOT-563	SYMBOL	E	F	P	P0	P1	T	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	0.20 ± 0.03	8.00 ± 0.30 -0.10	9.50 ± 1.00
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	0.008 ± 0.001	0.315 ± 0.012 -0.004	0.374 ± 0.039

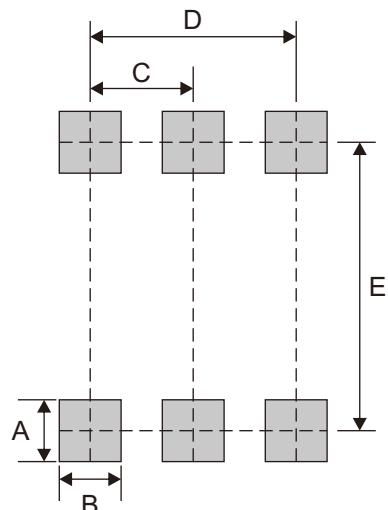
Marking Code

Part Number	Marking Code
ABC847BV-HF	K4V



Suggested P.C.B. PAD Layout

SIZE	SOT-563	
	(mm)	(inch)
A	0.30	0.012
B	0.30	0.012
C	0.50	0.020
D	1.00	0.039
E	1.40	0.055



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-563	3,000	7